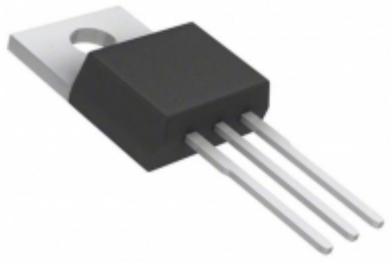



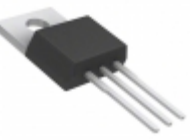



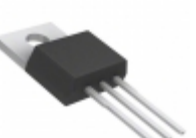
	<h2 style="color: red;">FQP65N06</h2> <p><b>Hersteller-Teilenummer:</b> <a href="#">FQP65N06</a></p> <p><b>Hersteller / Marke:</b> <a href="#">Fairchild/ON Semiconductor</a></p> <p><b>Teil der Beschreibung:</b> MOSFET N-CH 60V 65A TO-220</p> <p><b>Datenblätter:</b> <a href="#">1.FQP65N06.pdf</a> <a href="#">2.FQP65N06.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 93126 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	<a href="#">FQP65N06</a>
Hersteller	<a href="#">Fairchild/ON Semiconductor</a>
Beschreibung	MOSFET N-CH 60V 65A TO-220
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	93126 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Supplier Device-Gehäuse	TO-220AB
Verlustleistung (max)	150W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	65A (Tc)
Rds On (Max) @ Id, Vgs	16 mOhm @ 32.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	65nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2410pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±25V
Verpackung	Tube

FQP65N06 ist neu im Original, Suche FQP65N06 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQP65N06 Fairchild/ON Semiconductor mit Garantie und Vertrauen.  
Anfrage FQP65N06: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>FQP630TSTU</b> Fairchild/ON Semiconductor MOSFET N-CH 200V 9A TO-220</p>	 <p><b>FQP630TSTU</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 9A TO-220</p>	 <p><b>FQP630</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 9A TO-220</p>	 <p><b>FQP630</b> Fairchild/ON Semiconductor MOSFET N-CH 200V 9A TO-220</p>
 <p><b>FQP6N25</b> Fairchild/ON Semiconductor MOSFET N-CH 250V 5.5A TO-220</p>	 <p><b>FQP6N15</b> Fairchild/ON Semiconductor MOSFET N-CH 150V 6.4A TO-220</p>	 <p><b>FQP6N15</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 6.4A TO-220</p>	 <p><b>FQP65N06</b> AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 65A TO-220</p>

### heiße Teile

Mehr

<a href="#">FQP4N65C</a>	<a href="#">FQP4N90C</a>	<a href="#">FQP4N90C</a>	<a href="#">FQP50N03</a>	<a href="#">FQP50N03C</a>
<a href="#">FQP50N06</a>	<a href="#">FQP50N06</a>	<a href="#">FQP50N06L</a>	<a href="#">FQP50N06L</a>	<a href="#">FQP50N08</a>
<a href="#">FQP55N06</a>	<a href="#">FQP55N06</a>	<a href="#">FQP55N10</a>	<a href="#">FQP55N10</a>	<a href="#">FQP58N08</a>
<a href="#">FQP58N08</a>	<a href="#">FQP5N20L</a>	<a href="#">FQP5N20L</a>	<a href="#">FQP5N50C</a>	<a href="#">FQP5N50C</a>
<a href="#">FQP5N60C</a>	<a href="#">FQP5N60C</a>	<a href="#">FQP630TSTU</a>	<a href="#">FQP630TSTU</a>	<a href="#">FQP65N06</a>
<a href="#">FQP6N40C</a>	<a href="#">FQP6N40C</a>	<a href="#">FQP6N40CF</a>	<a href="#">FQP6N40CF</a>	<a href="#">FQP6N50C</a>
<a href="#">FQP6N50C</a>	<a href="#">FQP6N60C</a>	<a href="#">FQP6N60C</a>	<a href="#">FQP6N80C</a>	<a href="#">FQP6N80C</a>
<a href="#">FQP6N90C</a>	<a href="#">FQP6N90C</a>	<a href="#">FQP70N03L</a>	<a href="#">FQP70N06</a>	<a href="#">FQP70N06C</a>
<a href="#">FQP70N08</a>	<a href="#">FQP70N08</a>	<a href="#">FQP70N10</a>	<a href="#">FQP70N10</a>	<a href="#">FQP7N10L</a>
<a href="#">FQP7N10L</a>	<a href="#">FQP7N20L</a>	<a href="#">FQP7N20L</a>	<a href="#">FQP7N60C</a>	<a href="#">FQP7N65C</a>

Contact us: [Info@Y-IC.com](mailto:Info@Y-IC.com)

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